



## DESCRIPTION

The A7340 is a monolithic step-down DC/DC converter designed to provide low EMI performance and deliver up to 4 A of output current without requiring an external power transistor, helping to reduce board space. It supports 100% duty-cycle operation for low-dropout applications. An internal soft-start function minimizes inrush current during startup, extending battery life in portable systems. For enhanced reliability, the A7340 integrates cycle-by-cycle peak current limiting, short-circuit protection, thermal shutdown protection, and undervoltage lockout (UVLO).

The device is available in a 8-pin small profile SOP8 package.

## ORDERING INFORMATION

| Package Type                   | Part Number                               |           |
|--------------------------------|-------------------------------------------|-----------|
| SOP8<br>SPQ:4,000pcs/Reel      | M8                                        | A7340M8R  |
|                                |                                           | A7340M8VR |
| Note                           | V: Halogen free Package<br>R: Tape & Reel |           |
| AiT provides all RoHS products |                                           |           |

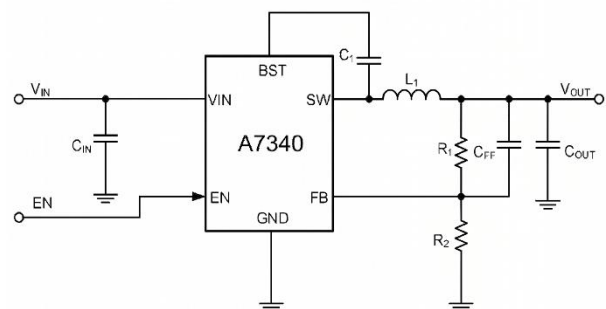
## FEATURES

- Wide input voltage Range: 4V~30V
- Adjustable Output Voltage from 0.8V to  $V_{IN}$
- Low  $R_{DS(ON)}$  Switches 57m $\Omega$  / 43m $\Omega$
- 520KHz Typical Switching Frequency
- Internal Power-Save Mode (PFM/PWM)
- Duty Cycle up to 100%
- COT Mode
- Short Circuit Protection
- Over Current Protection
- Internal Soft Startup
- Thermal Shutdown Protection

## APPLICATION

- LCD Monitor and LCDTV
- Battery-powered Equipment
- Digital Home Appliances: Digital TVs
- ADSL Modem Portable Instruments

## TYPICAL APPLICATION

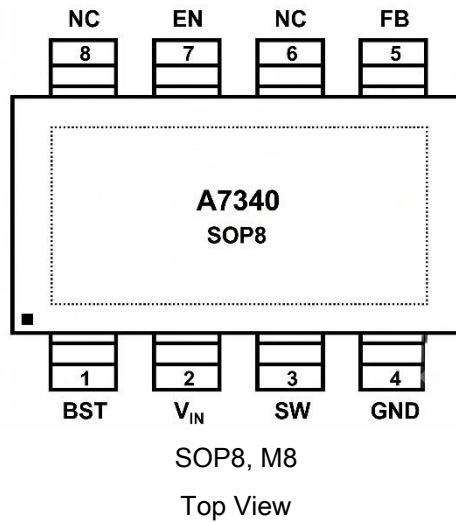


$V_{IN}=30V$  ;  $V_{OUT}=3.3V$ / 4A,  $L1=$ WSL06040-6R8M (6.8uH)

$V_{IN}=30V$  ;  $V_{OUT}=5.0V$ / 4A,  $L1=$ WSL06040-6R8M (6.8uH)

$V_{IN}=30V$  ;  $V_{OUT}=12V$ / 4A,  $L1=$  WSL12040-120M (12uH)

or WSL10040-150M (15uH)

**PIN DESCRIPTION**

| PIN# | Symbol          | Function                                                                                                                           |
|------|-----------------|------------------------------------------------------------------------------------------------------------------------------------|
| 1    | BST             | Bootstrap. A capacitor connected between SW and BST pins is required to form a floating supply across the high-side switch driver. |
| 2    | V <sub>IN</sub> | Power supply voltage input.                                                                                                        |
| 3    | SW              | Switch pin connected to the internal FET switches and inductor terminal. Connect the inductor of the output filter to this pin.    |
| 4    | GND             | Ground pin.                                                                                                                        |
| 5    | FB              | Feedback pin for the internal control loop. Connect this pin to an external feedback divider.                                      |
| 6, 8 | NC              | Non function Pin                                                                                                                   |
| 7    | EN              | Device enable logic input. Logic high enables the device, logic low disables the device and turns it into shutdown.                |

**ABSOLUTE MAXIMUM RATINGS**

Over operating free-air temperature range (unless otherwise noted)

|                                                                   |                               |
|-------------------------------------------------------------------|-------------------------------|
| V <sub>IN</sub> , and EN pin Voltage                              | -0.3V ~ 36V                   |
| BST, Voltage                                                      | V <sub>SW</sub> +5V           |
| SW (less than 10ns) , Voltage                                     | -0.3V ~ V <sub>IN</sub> +0.5V |
| FB, Voltage                                                       | - 0.3V ~ +6.5V                |
| T <sub>J</sub> , Operating Junction Temperature                   | -40°C ~ +150°C                |
| T <sub>STG</sub> , Storage Temperature                            | -65°C ~ +150°C                |
| R <sub>θJA</sub> , Junction-to-Ambient Thermal Resistance         | 48.4°C/W                      |
| R <sub>θJC</sub> (top), Junction-to-Case (Top) Thermal Resistance | 52.5°C/W                      |

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**RECOMMENDED OPERATING CONFITIONS**

T<sub>C</sub>= 25°C, unless otherwise specified.

| Parameter                      | Symbol          | Conditions | Min | Typ | Max | Unit |
|--------------------------------|-----------------|------------|-----|-----|-----|------|
| Operating Junction Temperature | -               | -          | -40 | -   | 125 | °C   |
| Operating temperature range    | -               | -          | -40 | -   | 85  | °C   |
| Input Voltage                  | V <sub>IN</sub> | -          | 4.5 | -   | 30  | V    |
| Output Voltage                 | -               | -          | 0   | -   | 4   | A    |

**ELECTRICAL CHARACTERISTICS**

$V_{IN} = 12V$ , unless otherwise specified. Typical values are at  $T_A = 25^{\circ}C$

| Parameter                                        | Symbol                    | Test Condition           | Min. | Typ. | Max. | Units |
|--------------------------------------------------|---------------------------|--------------------------|------|------|------|-------|
| Input voltage range                              | V <sub>IN</sub>           | -                        | 4    | -    | 30   | V     |
| Non switching quiescent current                  | I <sub>Q</sub>            | EN = 5V                  | 200  | 240  | 300  | μA    |
| Shutdown current                                 | I <sub>OFF</sub>          | EN = GND                 | -    | 1    | 3    | μA    |
| Regulated Feedback Voltage                       | V <sub>FB</sub>           | -                        | 785  | 800  | 815  | mV    |
| V <sub>IN</sub> under voltage lockout            | V <sub>IN(UVLO)</sub>     | -                        | -    | 3.2  | -    | V     |
| V <sub>IN</sub> under voltage lockout Hysteresis |                           | -                        | -    | 380  | -    | mV    |
| ENABLE (EN PIN)                                  |                           |                          |      |      |      |       |
| Enable threshold                                 | V <sub>(EN_RISING)</sub>  | Rising                   | 1.2  | -    | -    | V     |
|                                                  | V <sub>(EN_FALLING)</sub> | Falling                  | -    | -    | 0.4  | V     |
| Threshold Hysteresis                             | V <sub>(EN_HYS)</sub>     | -                        | -    | 120  | -    | mV    |
| POWER STAGE                                      |                           |                          |      |      |      |       |
| High-side FET on resistance                      | R <sub>(HSD)</sub>        | I <sub>SW</sub> =1000mA  | -    | 57   | -    | mΩ    |
| Low-side FET on resistance                       | R <sub>(LSD)</sub>        | I <sub>SW</sub> =-1000mA | -    | 43   | -    | mΩ    |
| CURRENT LIMIT                                    |                           |                          |      |      |      |       |
| FET current limit                                | I <sub>(LIM_HS)</sub>     | FB=90%                   | -    | 7    | -    | A     |
| OSCILLATOR                                       |                           |                          |      |      |      |       |
| Centre switching frequency                       | F <sub>SW</sub>           | -                        | 450  | 520  | 600  | KHz   |
| OVER TEMPERATURE PROTECTION                      |                           |                          |      |      |      |       |
| Rising temperature                               | Thermal                   | -                        | -    | 160  | -    | °C    |
| Hysteresis                                       | Shutdown                  | -                        | -    | 30   | -    | °C    |
| Soft start                                       | -                         | -                        | -    | 3    | -    | ms    |



## TYPICAL PERFORMANCE CHARACTERISTICS

Fig 1. Load Transient Response

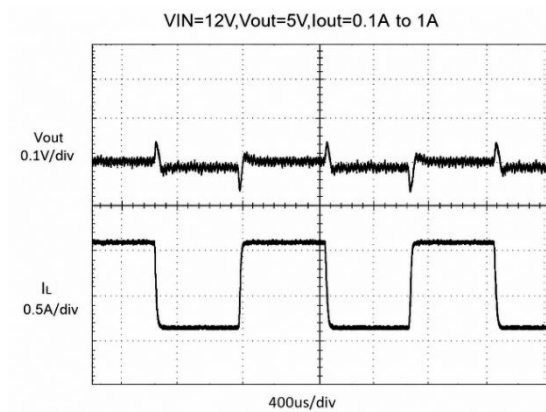


Fig 2. Load Transient Response

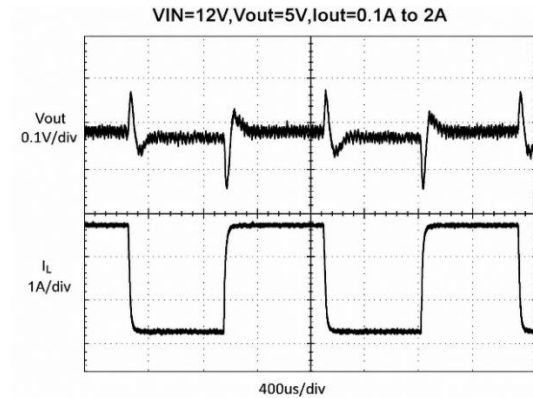


Fig 3. Load Transient Response

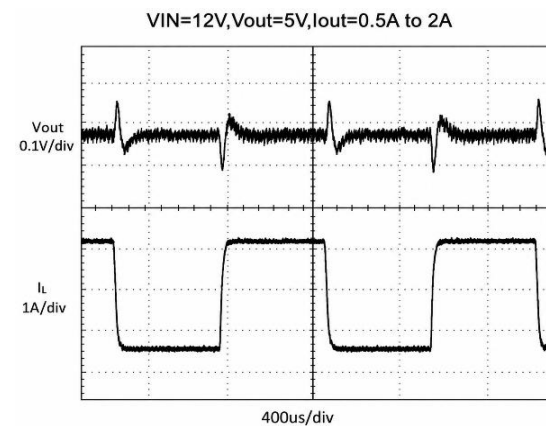


Fig 4. Load Transient Response

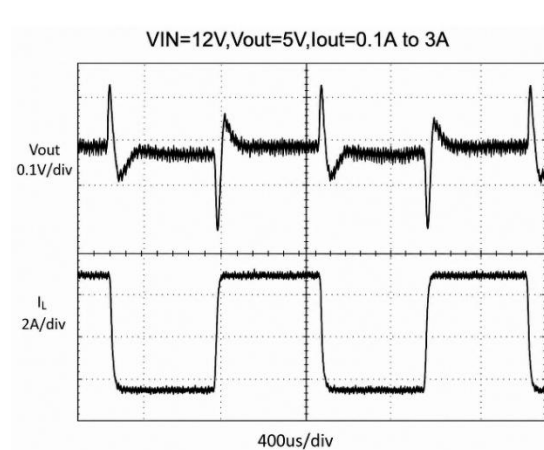


Fig 5. Load Transient Response

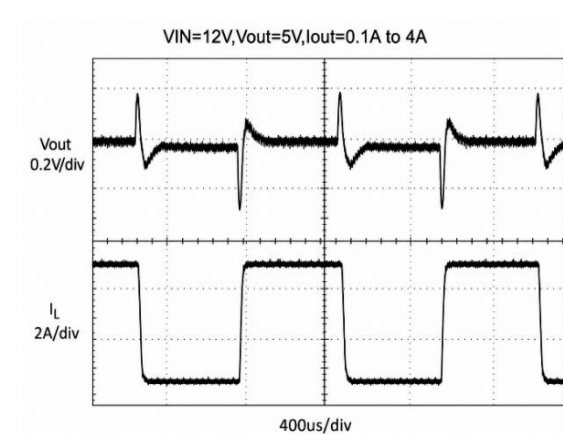


Fig 6. Load Transient Response

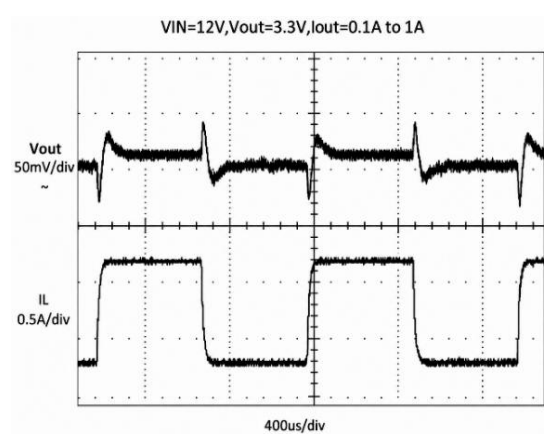




Fig 7. Load Transient Response

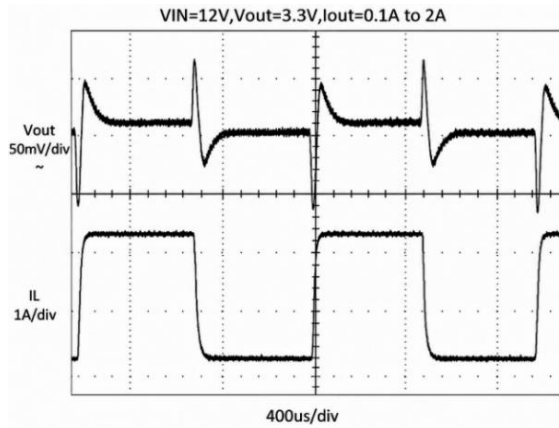


Fig 8. Load Transient Response

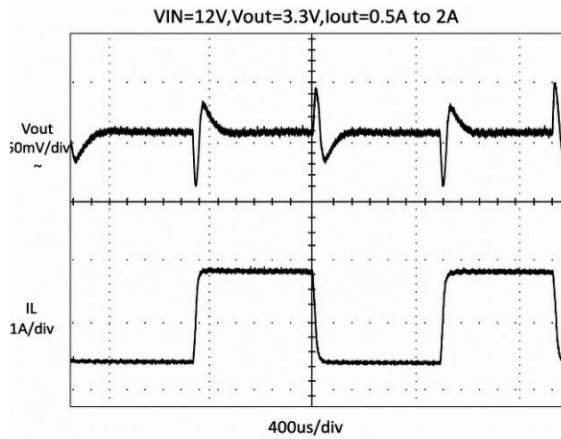


Fig 9. Load Transient Response

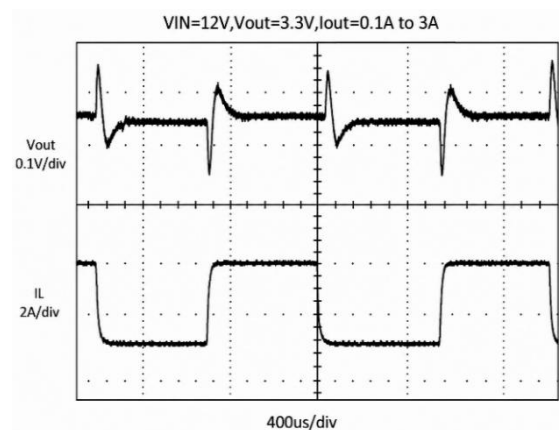


Fig 10. Load Transient Response

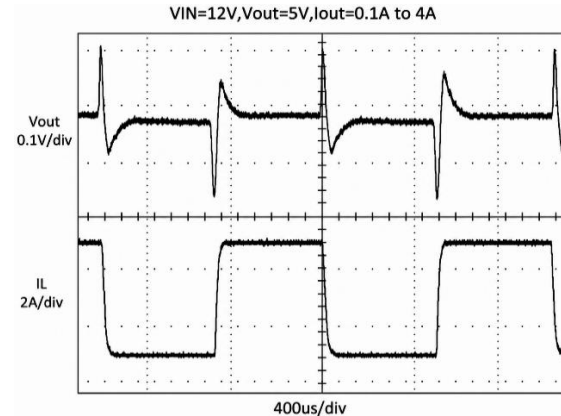


Fig 11. Steady State Test

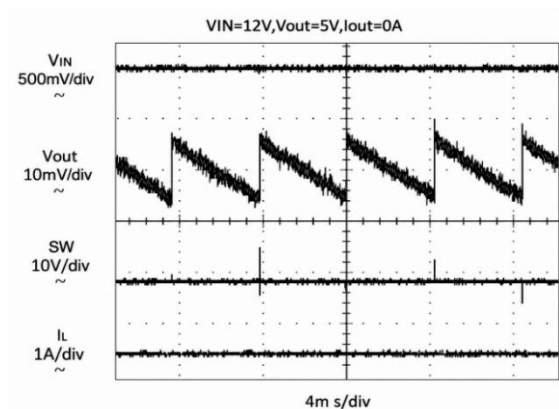


Fig 12. Steady State Test

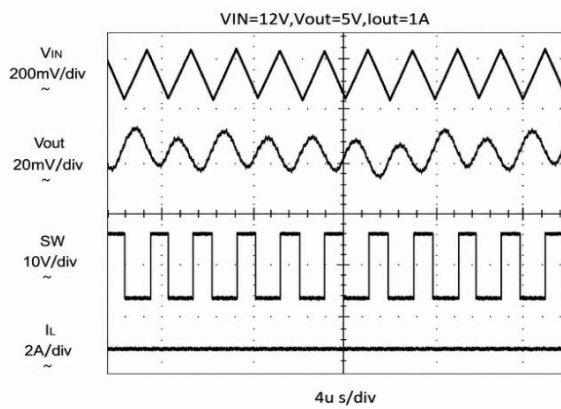




Fig 13. Steady State Test

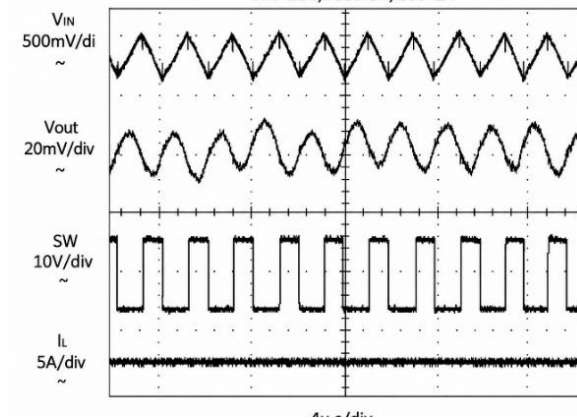


Fig 14. Steady State Test

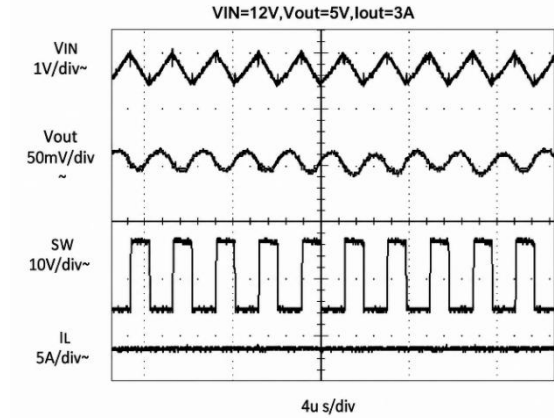


Fig 15. Steady State Test

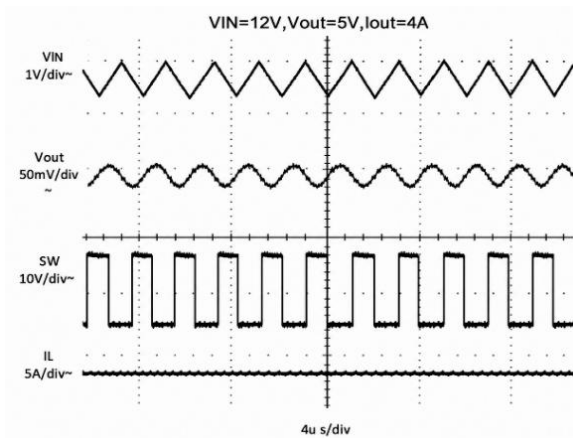


Fig 16. Steady State Test

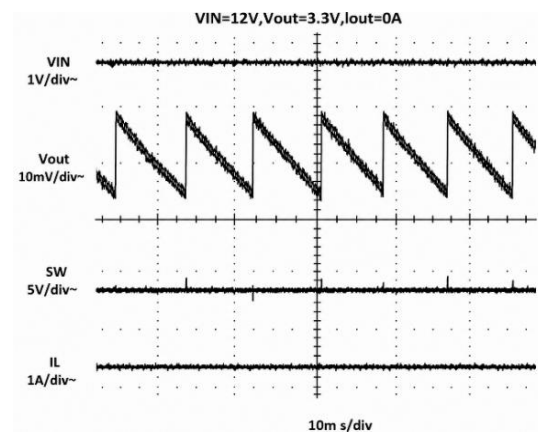


Fig 17. Steady State Test

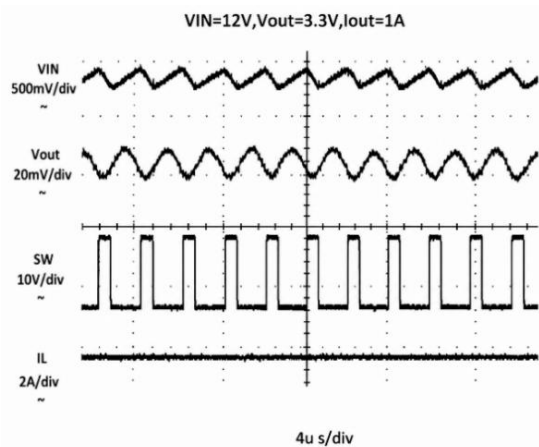


Fig 18. Steady State Test

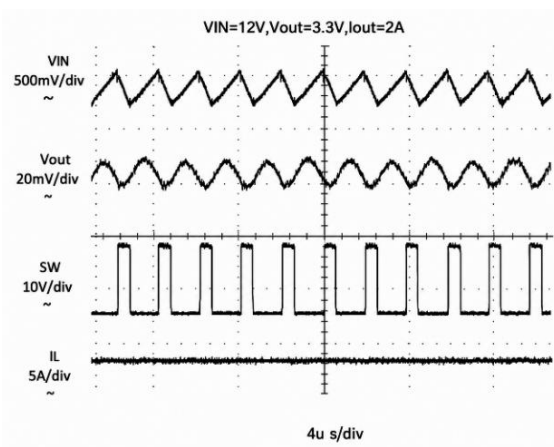




Fig 19. Steady State Test

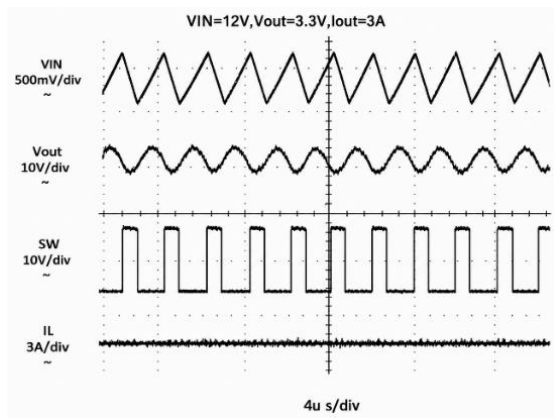


Fig 20. Steady State Test

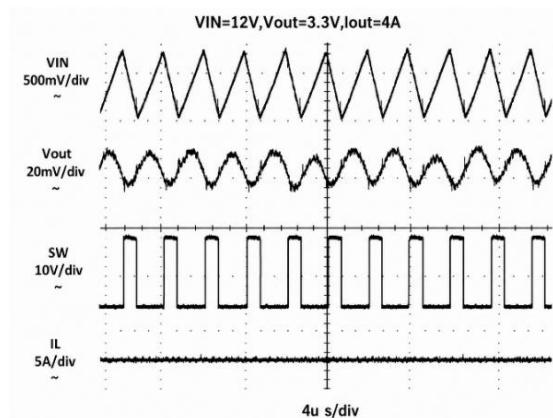


Fig 21. Short Circuit Entry

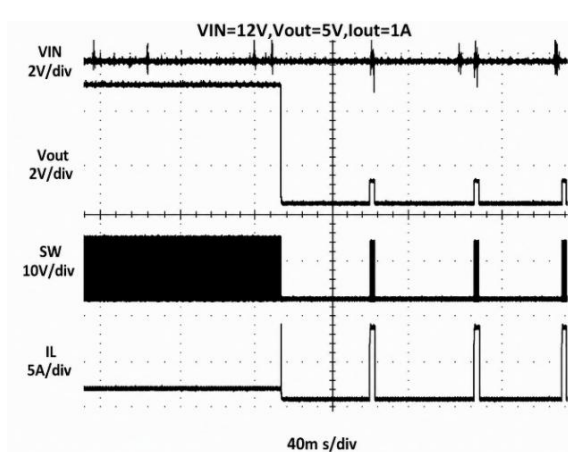


Fig 22. Short Circuit Exit

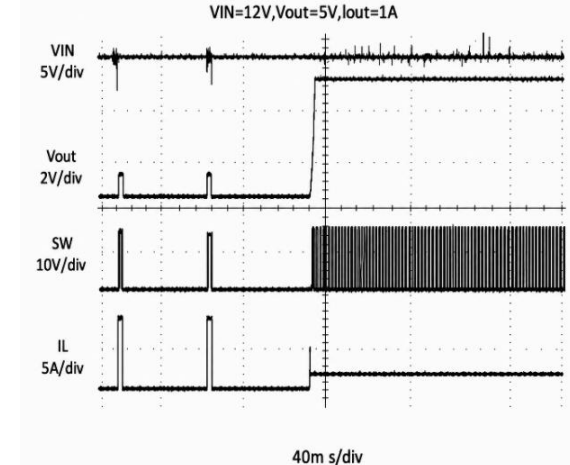


Fig 23. Short Circuit Steady

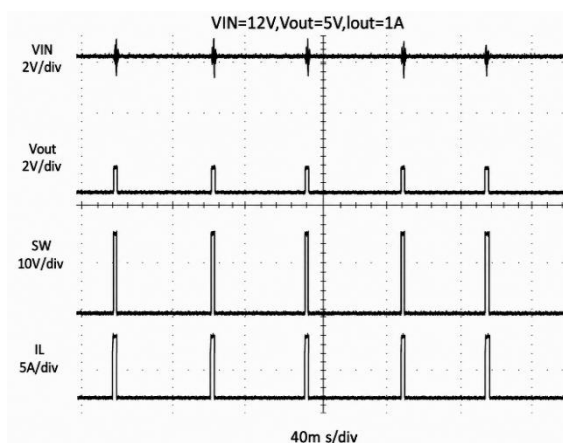


Fig 24. Vin Power On

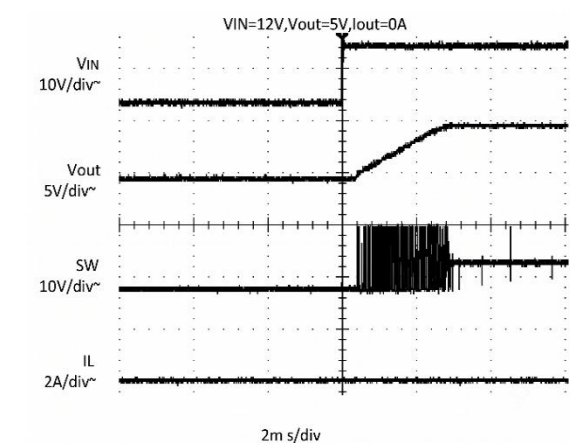




Fig 25. Vin Power On

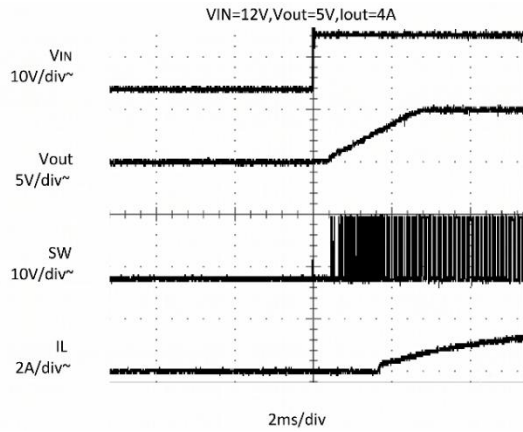


Fig 26. Vin Power Off

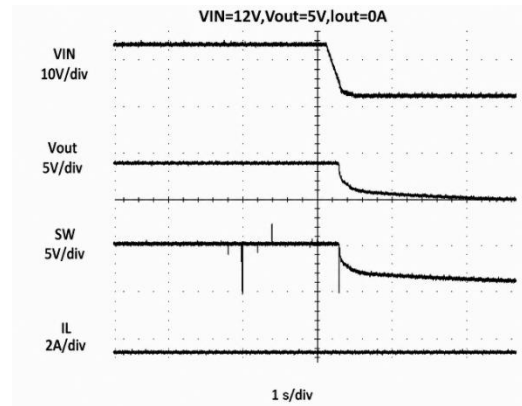


Fig 27. Vin Power Off

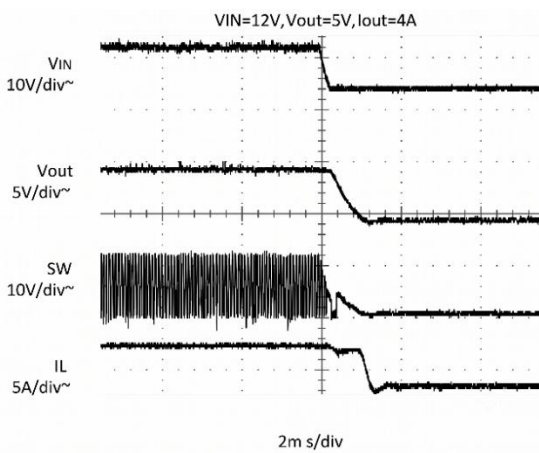


Fig 28. Vin Power On

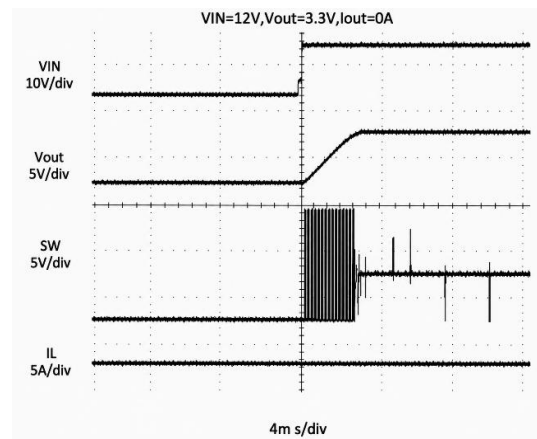


Fig 29. Vin Power On

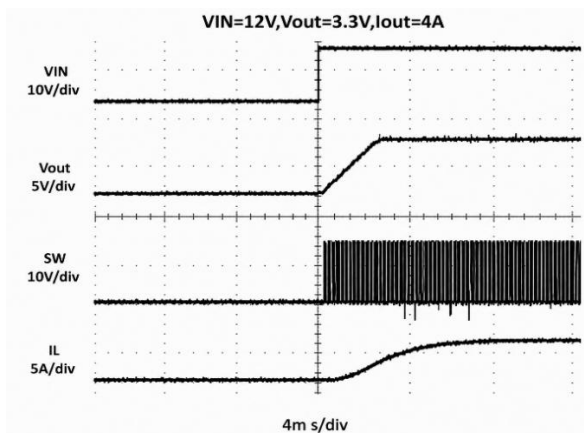


Fig 30. Vin Power Off

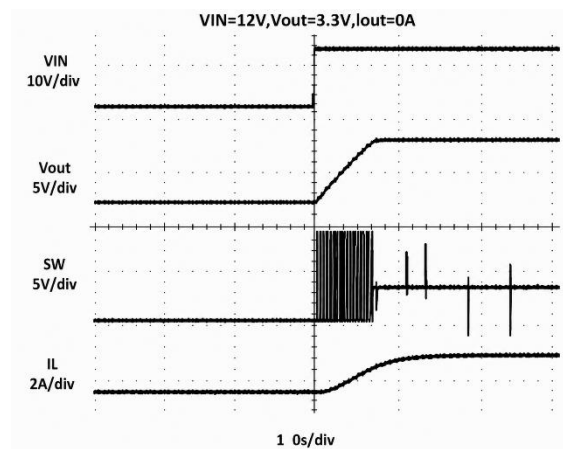




Fig 31. Vin Power Off

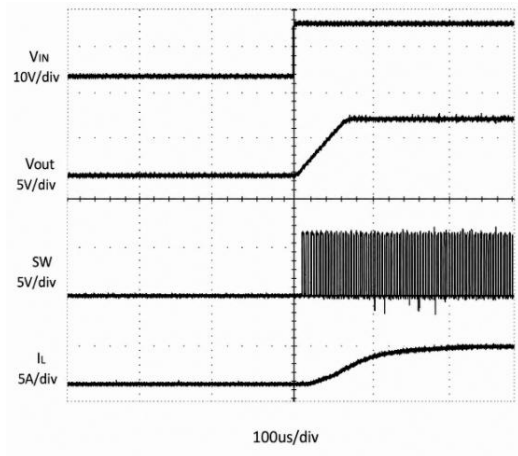


Fig 32. EN ON

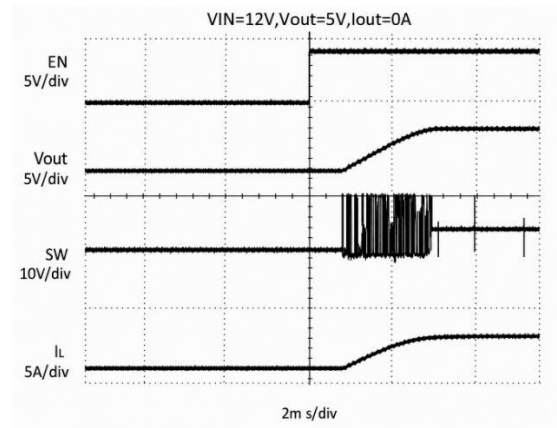


Fig 33. EN ON

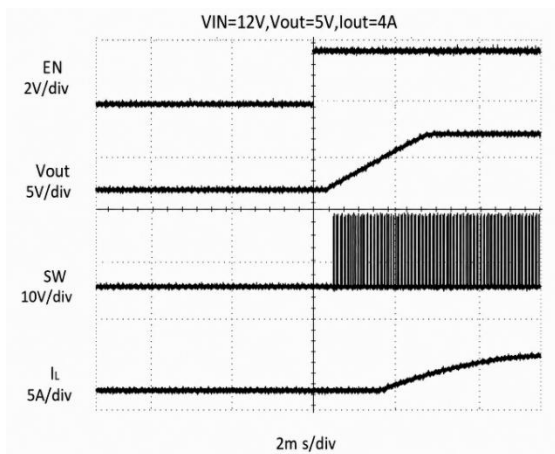


Fig 34. EN OFF

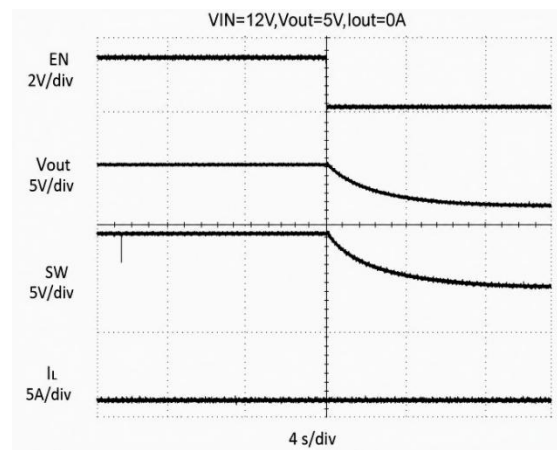


Fig 35. EN OFF

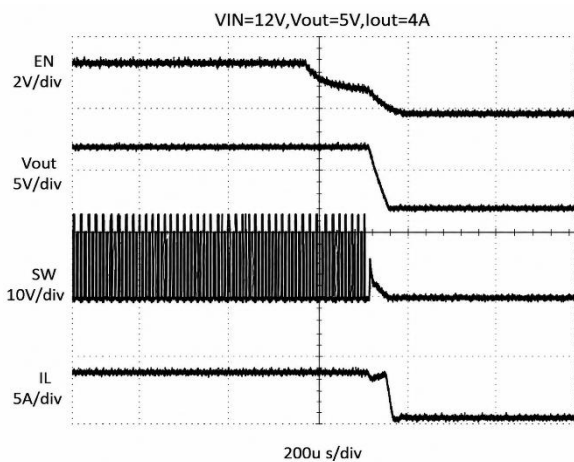


Fig 36. EN ON

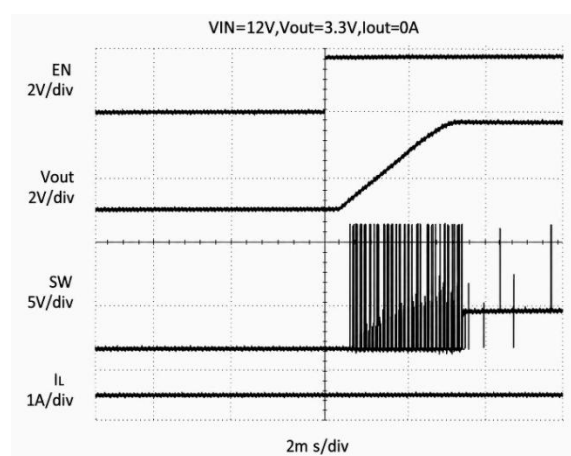




Fig 37. EN ON

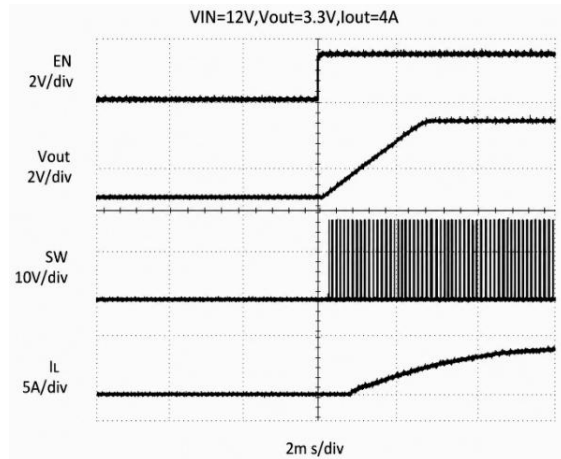


Fig 38. EN OFF

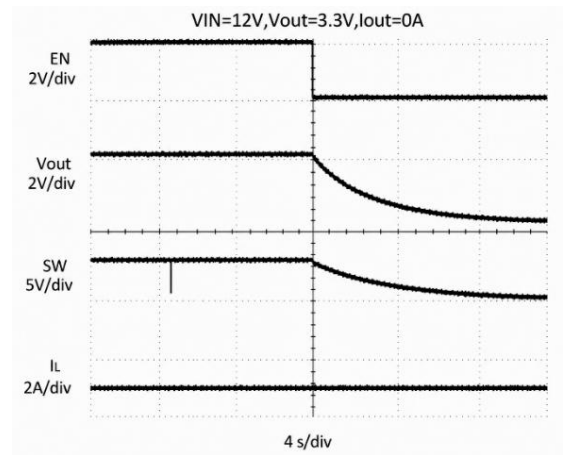
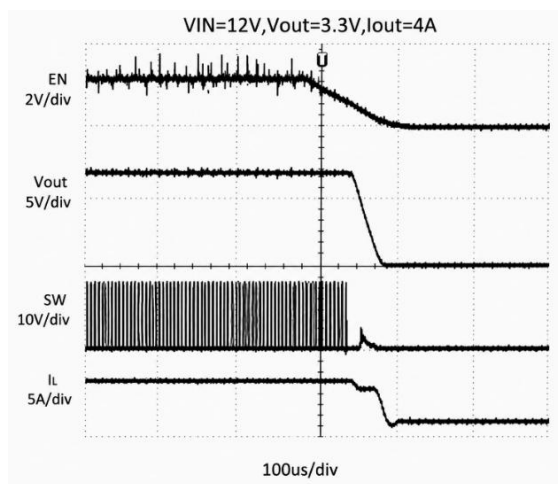
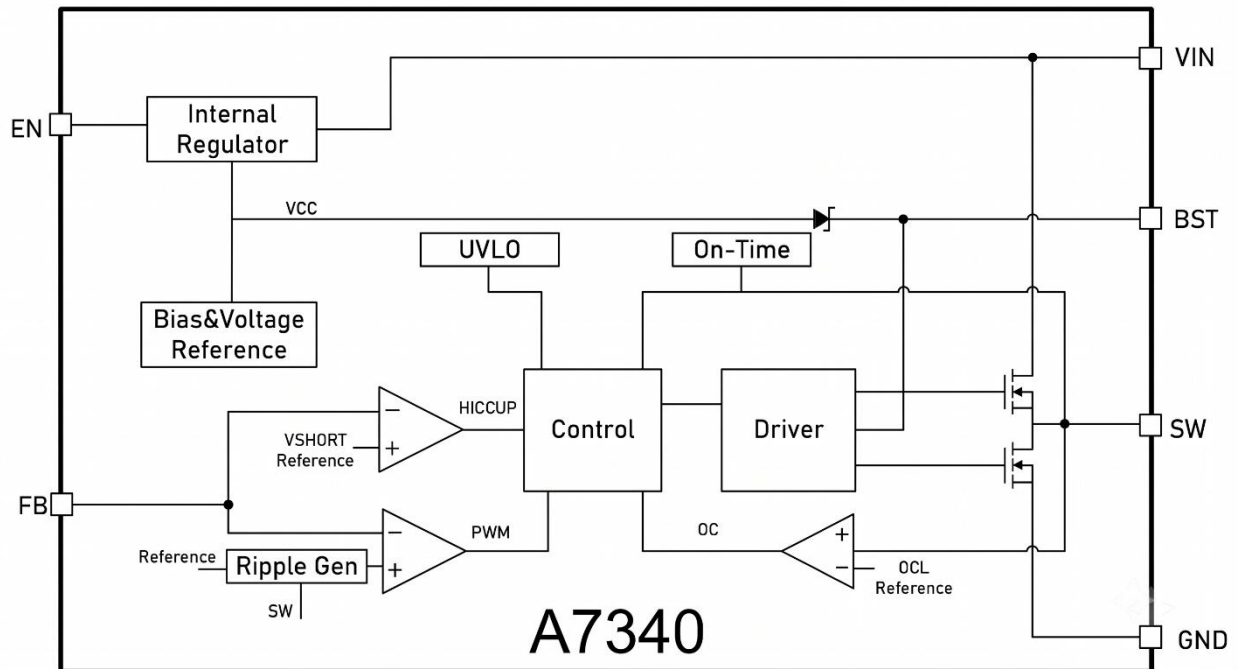


Fig 39. EN OFF





## BLOCK DIAGRAM





## DETAILED INFORMATION

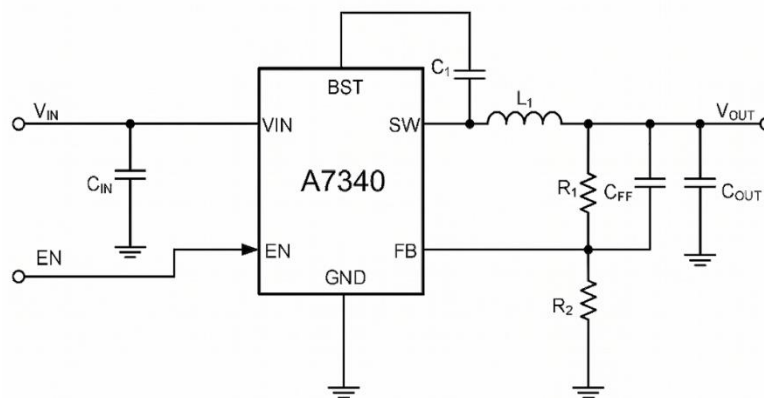
### Overview

The A7340 is a high-output-current monolithic step-down DC/DC converter capable of delivering up to 4 A of continuous output current from an input voltage range of 4 V to 30 V. The device operates at a fixed switching frequency of 520 kHz and employs a slope-compensated current-mode control architecture to provide excellent line and load regulation. The EN (Enable) pin allows the device to be controlled by standard logic signals, enabling low-power standby operation when disabled. Internal loop compensation eliminates the need for external compensation components, simplifying circuit design. For enhanced reliability, the A7340 integrates cycle-by-cycle current limiting, thermal shutdown protection, and frequency foldback under short-circuit conditions. When the current limit is triggered and the feedback voltage (VFB) falls below 0.8 V, the switching frequency is automatically reduced to minimize power dissipation and improve short-circuit protection.

### Application information

The A7340 is a high-performance, monolithic step-down DC/DC converter featuring a wide input voltage range of 4 V to 30 V and capable of delivering up to 4 A of continuous output current. Operating at a fixed switching frequency of 520 kHz, the A7340 requires only a few external components, including an input capacitor ( $C_{IN}$ ), an output capacitor ( $C_{OUT}$ ), and an inductor ( $L_1$ ), enabling a compact and cost-effective power supply design. The output voltage is adjustable from 0.8 V up to  $V_{IN}$  through an external resistor divider.

$$V_{OUT} = 0.8 \times \frac{R_1 + R_2}{R_2}$$



**Table 1. Recommended Component Values**

| V <sub>OUT</sub> (V) | L1 (μH)  | C1(μF) | C <sub>IN</sub> (μF) | C <sub>OUT</sub> (μF) | C <sub>FF</sub> Opt.(pF) | R1 (kΩ) | R2 (kΩ) |
|----------------------|----------|--------|----------------------|-----------------------|--------------------------|---------|---------|
| 3.3                  | 1.5 ~ 10 | 0.1    | 22                   | 22+22                 | 10 ~ 100                 | 100     | 32      |
| 5                    | 2.2 ~ 10 | 0.1    | 22                   | 22+22                 | 10 ~ 100                 | 100     | 19.1    |
| 12                   | 6.8 ~ 15 | 0.1    | 22                   | 22+22                 | 10 ~ 100                 | 180     | 13      |

**Note :** Recommended Inductor Selection and it for reference, the inductor value should be determined according to the specific circuit design requirements.

1. V<sub>IN</sub>=30V ; V<sub>OUT</sub>=3.3V/ 4A, L1=WSL06040-6R8M (6.8uH)
2. V<sub>IN</sub>=30V ; V<sub>OUT</sub>=5.0V/ 4A, L1=WSL06040-6R8M (6.8uH)
3. V<sub>IN</sub>=30V ; V<sub>OUT</sub>=12V/ 4A, L1= WSL12040-120M (12uH), WSL10040-150M (15uH)

### Power Supply Recommendations

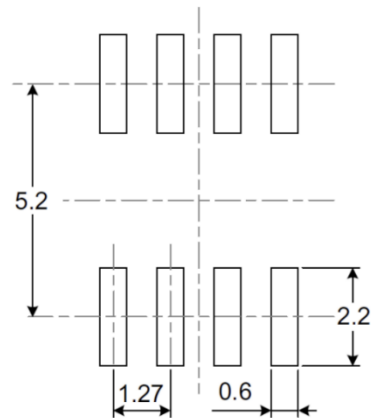
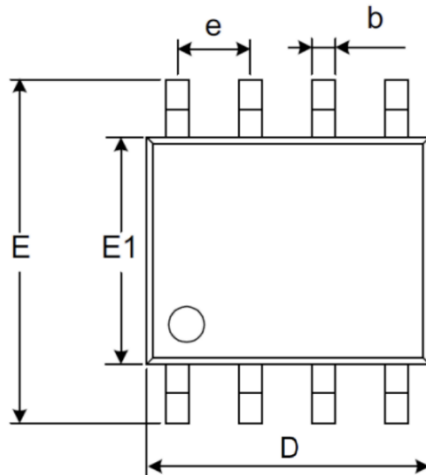
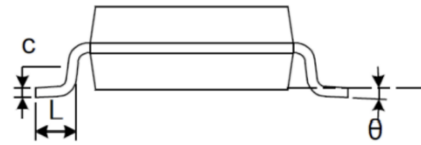
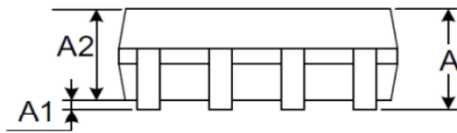
The A7340 designed to operate from an input voltage supply range between 4V and 30V. This input supply must be well regulated. If the input supply is located more than a few inches from the device or converter, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. An electrolytic capacitor with a value of 47 μF is a typical choice.

### Layout Guidelines

- V<sub>IN</sub> and GND traces should be as wide as possible to reduce trace impedance. The wide areas are also of advantage from the viewpoint of heat dissipation.
- The input capacitor and output capacitor should be placed as close to the device as possible to minimize trace impedance.
- Provide sufficient vias for the input capacitor and output capacitor.
- Keep the SW trace as physically short and wide as practical to minimize radiated emissions.
- Do not allow switching current to flow under the device.
- A separate V<sub>OUT</sub> path should be connected to the upper feedback resistor.
- Make a Kelvin connection to the GND pin for the feedback path.
- Voltage feedback loop should be placed away from the high-voltage switching trace, and preferably has ground shield.
- The trace of the VFB node should be as small as possible to avoid noise coupling.
- The GND trace between the output capacitor and the GND pin should be as wide as possible to minimize its trace impedance.

**PACKAGE INFORMATION**

Dimension in SOP8 (Unit: mm):

**RECOMMEND LAND PATTERN**

| Symbol | Millimeters |       |
|--------|-------------|-------|
|        | Min         | Max   |
| A      | 1.350       | 1.750 |
| A1     | 0.100       | 0.250 |
| A2     | 1.350       | 1.550 |
| b      | 0.330       | 0.510 |
| c      | 0.170       | 0.250 |
| D      | 4.800       | 5.000 |
| E      | 5.800       | 6.200 |
| E1     | 3.800       | 4.000 |
| e      | 1.270 BSC   |       |
| L      | 0.400       | 1.270 |
| θ      | 0°          | 8°    |

**IMPORTANT NOTICE**

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